

**225W SURFACE MOUNT TRANSIENT VOLTAGE SUPPRESSOR  
POWERDI®**

### Features

- 225W Peak Pulse Power Dissipation (10µs x 1000µs waveform)
- 5.0V - 170V Standoff Voltages
- Excellent Clamping Capability
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **Patented Interlocking Clip Design for High Surge Capacity, US Patent #7,095,113**

### Mechanical Data

- Case: POWERDI123
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: Cathode Band
- Terminals: Finish — Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.01 grams (approximate)

POWERDI123



Top View

### Ordering Information (Note 4)

Part Number	Case	Packaging
DFLTxxxA-7*	POWERDI123	3000/Tape & Reel

\* Add "-7" to the appropriate type number in Electrical Characteristics Table on page 2. Example: 10V reverse standoff device = DFLT10A-7.

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com>.

### Marking Information



Fxx = Product Type Marking Code,  
See Electrical Characteristics Table on Page 2  
YM = Date Code Marking  
Y = Year (ex: R = 2004)  
M = Month (ex: 9 = September)

#### Date Code Key

Year	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015	2016	2017	2018
Code	R	S	T	U	V	W	X	Y	Z	A	B	C	D	E	F
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec			
Code	1	2	3	4	5	6	7	8	9	O	N	D			

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Peak Pulse Power Dissipation (Note 5) 10/1000µs (Note 6) 8/20µs	P <sub>PK</sub>	225 1125	W
Peak Forward Surge Current, 8.3ms Single Half Sine Wave (Note 7)	I <sub>FSM</sub>	50	A
Instantaneous Forward Voltage @ I <sub>PP</sub> = 12A (Note 8)	V <sub>F</sub>	3.5	V

**Thermal Characteristics**

Characteristic	Symbol	Value	Unit
DC Steady-State Power Dissipation (Note 9)	P <sub>D</sub>	1.0	W
Thermal Resistance, Junction to Ambient (Note 9)	R <sub>θJA</sub>	125	°C/W
Thermal Resistance, Junction to Soldering Point (Note 10)	R <sub>θJS</sub>	6	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Part Number	Reverse Standoff Voltage	Breakdown Voltage V <sub>BR</sub> @ I <sub>T</sub> (Note 11)		Test Current	Max. Reverse Leakage @ V <sub>RWM</sub>	Max. Clamping Voltage @ I <sub>PP</sub>	Max. Peak Pulse Current I <sub>PP</sub>	Marking Code
	V <sub>RWM</sub> (V)	Min (V)	Max (V)	I <sub>T</sub> (mA)	I <sub>R</sub> (µA)	V <sub>C</sub> (V)	(A)	
DFLT5V0A	5.0	6.40	7.0	10	400	9.2	24.5	FAE
DFLT6V0A	6.0	6.67	7.37	10	400	10.3	21.8	FAG
DFLT6V5A	6.5	7.22	7.98	10	250	11.2	20.1	FAK
DFLT7V0A	7.0	7.78	8.60	10	100	12.0	18.8	FAM
DFLT7V5A	7.5	8.33	9.21	1.0	50	12.9	17.4	FAP
DFLT8V0A	8.0	8.89	9.83	1.0	25	13.6	16.5	FAR
DFLT8V5A	8.5	9.44	10.4	1.0	10	14.4	15.6	FAT
DFLT9V0A	9.0	10.0	11.1	1.0	5.0	15.4	14.6	FAV
DFLT10A	10	11.1	12.3	1.0	2.5	17.0	13.2	FAX
DFLT11A	11	12.2	13.5	1.0	2.5	18.2	12.4	FAZ
DFLT12A	12	13.3	14.7	1.0	2.5	19.9	11.3	FBE
DFLT13A	13	14.4	15.9	1.0	1.0	21.5	10.5	FBG
DFLT14A	14	15.6	17.2	1.0	1.0	23.2	9.7	FBK
DFLT15A	15	16.7	18.5	1.0	1.0	24.4	9.22	FBM
DFLT16A	16	17.8	19.7	1.0	1.0	26.0	8.65	FBP
DFLT17A	17	18.9	20.9	1.0	1.0	27.6	8.15	FBR
DFLT18A	18	20.0	22.1	1.0	1.0	29.2	7.71	FBT
DFLT20A	20	22.2	24.5	1.0	1.0	32.4	6.94	FBV
DFLT22A	22	24.4	26.9	1.0	1.0	35.5	6.34	FBX
DFLT24A	24	26.7	29.5	1.0	1.0	38.9	5.78	FBZ
DFLT26A	26	28.9	31.9	1.0	1.0	42.1	5.35	FCE
DFLT27A	27	30	33.15	1.0	1.0	43.7	5.15	FCF
DFLT28A	28	31.1	34.4	1.0	1.0	45.4	4.96	FCG
DFLT30A	30	33.3	36.8	1.0	1.0	48.4	4.65	FCX
DFLT33A	33	36.7	40.6	1.0	1.0	53.3	4.22	FCM
DFLT36A	36	40.0	44.2	1.0	1.0	58.1	3.87	FCP
DFLT40A	40	44.4	49.1	1.0	1.0	64.5	3.49	FCR
DFLT43A	43	47.8	52.8	1.0	1.0	69.4	3.24	FCT
DFLT45A	45	50.0	55.3	1.0	1.0	72.7	3.10	FCV
DFLT48A	48	53.3	58.9	1.0	1.0	77.4	2.91	FCX
DFLT51A	51	56.7	62.7	1.0	1.0	82.4	2.73	FCZ
DFLT170A	170	189	209	1.0	5.0	281	0.81	FDZ

- Notes:
5. Non-Repetitive current pulse as shown in figure 2 and derated above T<sub>A</sub> = +25°C as per figure 1.
  6. Non-Repetitive current pulse as shown in figure 3 and derated above T<sub>A</sub> = +25°C as per figure 1.
  7. I<sub>FSM</sub> = 40A for DFLT170A; I<sub>FSM</sub> = 50A for all other voltages.
  8. 1/2 sine wave (or equivalent square wave), pulse width = 8.3ms, duty cycle = 4 pulses/minute maximum.
  9. Device mounted on 1"x1", FR-4 PCB; 2 oz. Cu pad layout. Cathode pad dimensions 5.5mm x 3.5mm. Anode pad dimensions 2.25mm x 3.5mm.
  10. Theoretical R<sub>θJS</sub> calculated from the top center of the die straight down to the PCB/cathode tab solder junction.
  11. V<sub>BR</sub> measured at pulse test current I<sub>T</sub> with tp ≤ 5.0ms at T<sub>A</sub> = +25°C.

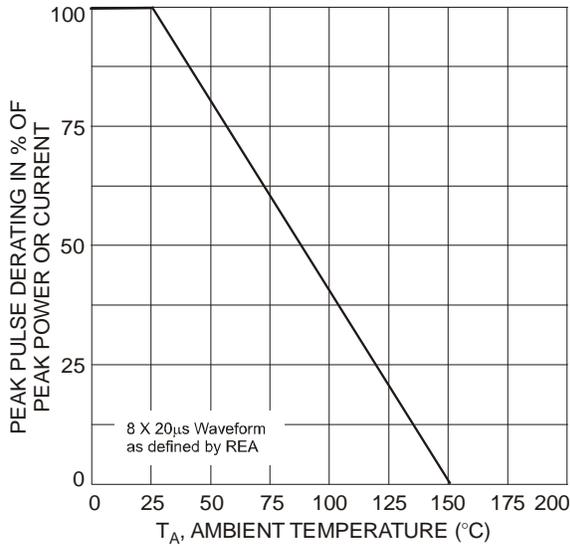


Fig. 1 Pulse Derating Curve

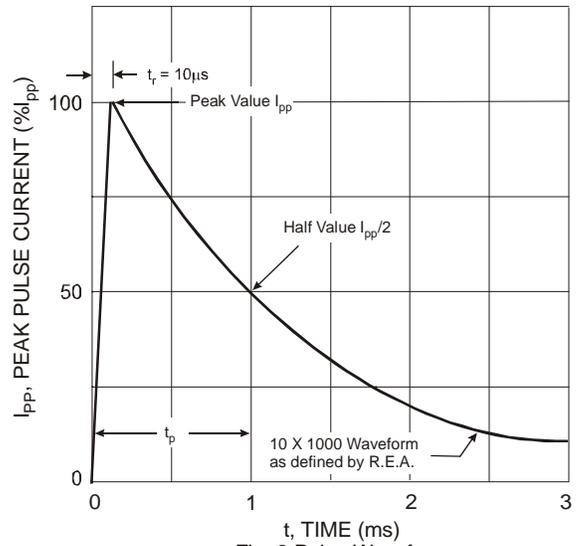


Fig. 2 Pulse Waveform

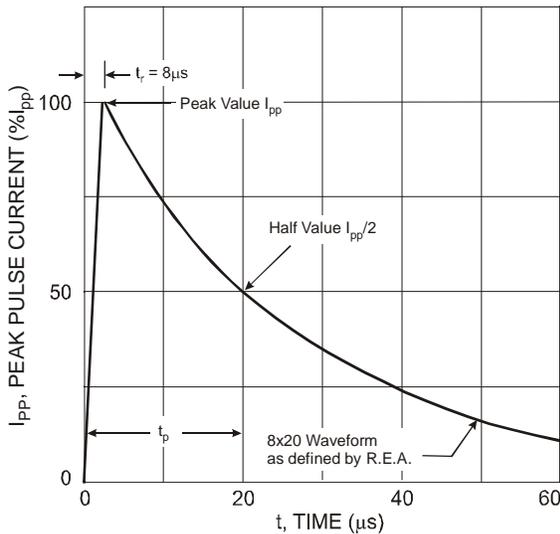


Fig. 3 Pulse Waveform

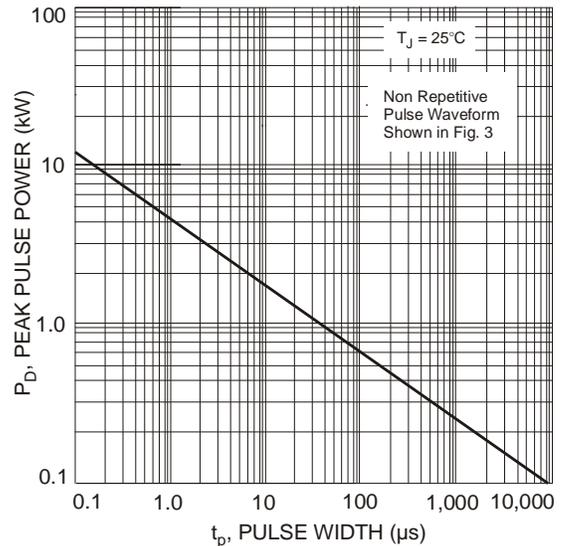


Fig. 4 Pulse Rating Curve

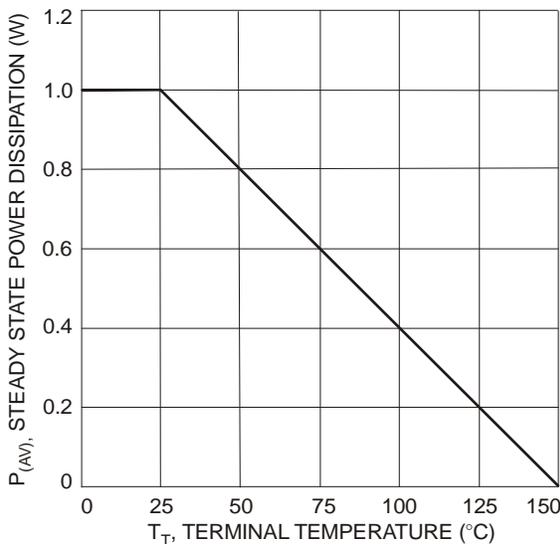


Fig. 5 Steady State Power Derating Curve

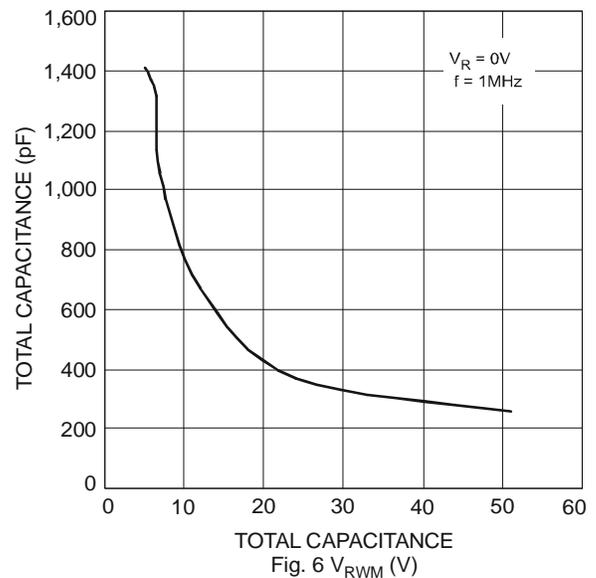


Fig. 6  $V_{RWM}$  (V)

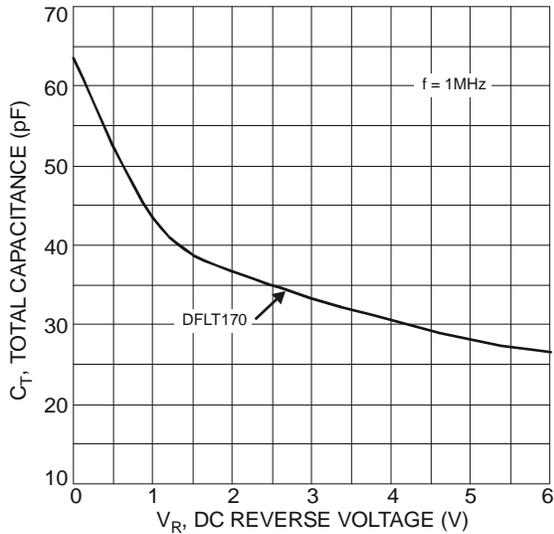
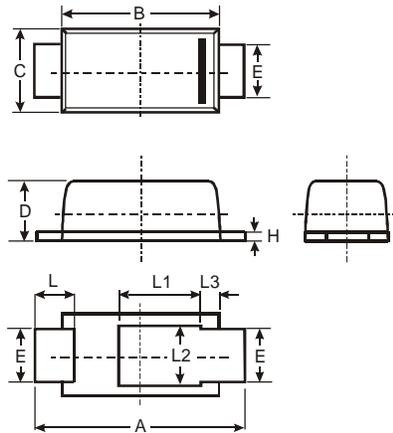


Fig. 7 Total Capacitance vs. Reverse Voltage

### Package Outline Dimensions

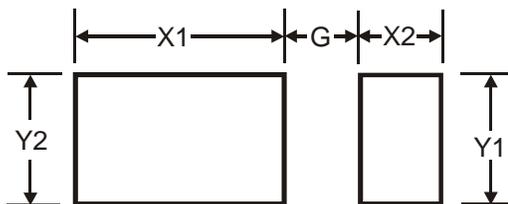
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



POWERDI123			
Dim	Min	Max	Typ
A	3.50	3.90	3.70
B	2.60	3.00	2.80
C	1.63	1.93	1.78
D	0.93	1.00	0.98
E	0.85	1.25	1.00
H	0.15	0.25	0.20
L	0.40	0.50	0.45
L1	-	-	1.35
L2	-	-	1.10
L3	-	-	0.20
All Dimensions in mm			

### Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
G	1.0
X1	2.2
X2	0.9
Y1	1.4
Y2	1.4

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